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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	F ² MC-16LX
Core Size	16-Bit
Speed	16MHz
Connectivity	CANbus, EBI/EMI, SCI, Serial I/O, UART/USART
Peripherals	POR, WDT
Number of I/O	81
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	A/D 8x8/10b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb90f548glspf-ge1

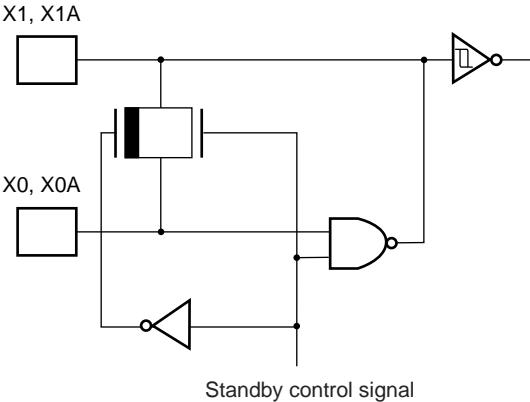
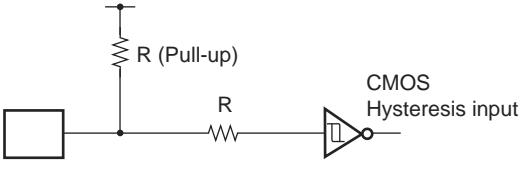
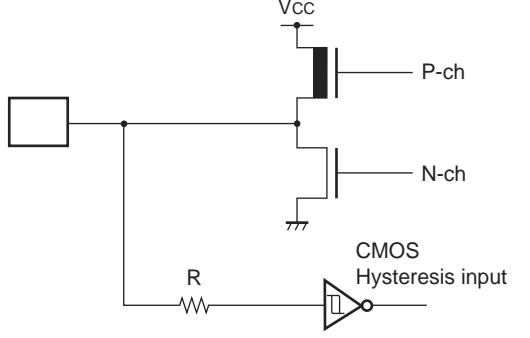
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Pin No.		Pin name	Circuit type	Function
LQFP ^{*2}	QFP ^{*1}			
72	74	P95	D	General I/O port. This function is always enabled.
		RX0		RX input pin for CAN0 Interface. When the CAN function is used, output from the other functions must be stopped.
73	75	P96	D	General I/O port. This function is enabled when CAN1 disables the output.
		TX1		TX output pin for CAN1. This function is enabled when CAN1 enables the output (only MB90540G series).
74	76	P97	D	General I/O port. This function is always enabled.
		RX1		RX input pin for CAN1 Interface. When the CAN function is used, output from the other functions must be stopped (only MB90540G series).
76	78	PA0	D	General I/O port. This function is always enabled.
32	34	AV _{cc}	Power supply	Power supply pin for the A/D Converter. This power supply must be turned on or off while a voltage higher than or equal to AV _{cc} is applied to V _{cc} .
35	37	AV _{ss}	Power supply	Power supply pin for the A/D Converter.
33	35	AVRH	Power supply	External reference voltage input pin for the A/D Converter. This power supply must be turned on or off while a voltage higher than or equal to AVRH is applied to AV _{cc} .
34	36	AVRL	Power supply	External reference voltage input pin for the A/D Converter.
47, 48	49, 50	MD0, MD1	C	Input pins for specifying the operating mode. The pins must be directly connected to V _{cc} or V _{ss} .
49	51	MD2	F	Input pin for specifying the operating mode. The pin must be directly connected to V _{cc} or V _{ss} .
25	27	C	—	Power supply stabilization capacitor pin. It should be connected externally to an 0.1 μF ceramic capacitor.
21, 82	23, 84	V _{cc}	Power supply	Input pin for power supply (5.0 V).
9, 40, 79	11, 42, 81	V _{ss}	Power supply	Input pin for power supply (0.0 V).

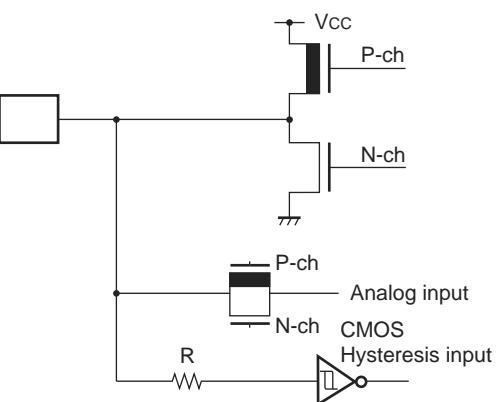
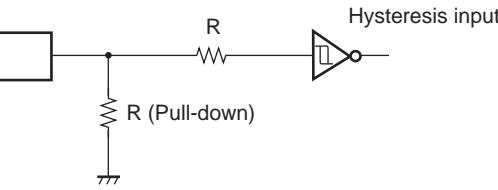
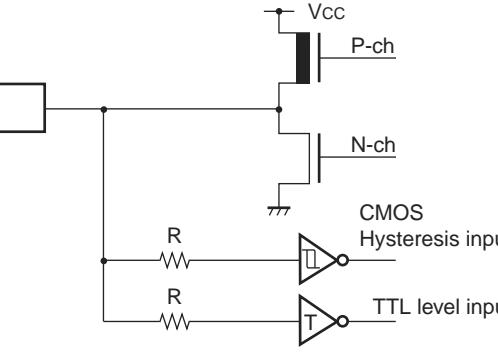
*1 : FPT-100P-M06

*2 : FPT-100P-M20

4. I/O Circuit Type

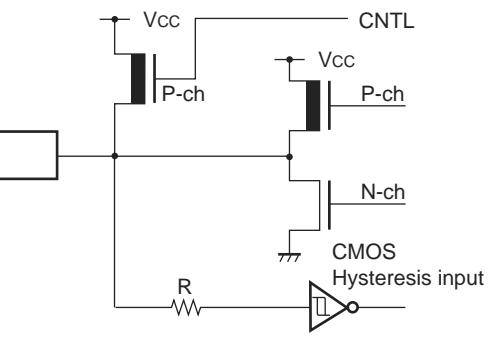
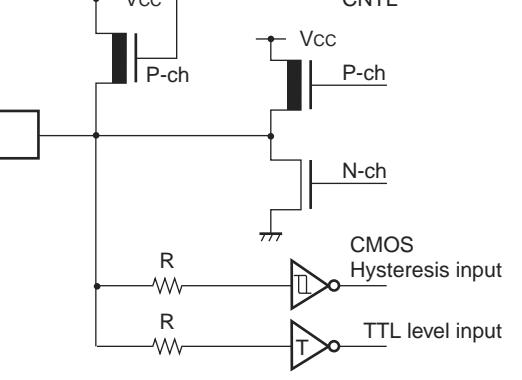
Circuit type	Diagram	Remarks
A	 <p>X1, X1A</p> <p>X0, X0A</p> <p>Standby control signal</p>	<ul style="list-style-type: none"> ■ High-speed oscillation feedback resistor : 1 MΩ approx. ■ Low-speed oscillation feedback resistor: 10 MΩ approx.
B	 <p>R (Pull-up)</p> <p>R</p> <p>CMOS Hysteresis input</p>	<ul style="list-style-type: none"> ■ CMOS Hysteresis input ■ Pull-up resistor : 50 kΩ approx.
C	 <p>R</p> <p>CMOS Hysteresis input</p>	<ul style="list-style-type: none"> ■ CMOS Hysteresis input
D	 <p>Vcc</p> <p>P-ch</p> <p>N-ch</p> <p>R</p> <p>CMOS Hysteresis input</p>	<ul style="list-style-type: none"> ■ CMOS level output ■ CMOS Hysteresis input

(Continued)

Circuit type	Diagram	Remarks
E	 <p>This circuit diagram shows a CMOS inverter (indicated by a square symbol) connected to the drain of a P-channel MOSFET (labeled "P-ch"). The source of this P-channel FET is connected to the drain of an N-channel MOSFET (labeled "N-ch"). The source of the N-channel FET is connected to ground. The gate of the N-channel FET is connected to the drain of another P-channel MOSFET (labeled "P-ch"), which is connected to the "Analog input". The source of this second P-channel FET is connected to the "CMOS Hysteresis input" through a resistor labeled "R". The "CMOS Hysteresis input" is also connected to ground.</p>	<ul style="list-style-type: none"> ■ CMOS level output ■ CMOS Hysteresis input ■ Analog input
F	 <p>This circuit diagram shows a CMOS inverter (square symbol) connected to the drain of a P-channel MOSFET (labeled "P-ch"). The source of this P-channel FET is connected to the drain of an N-channel MOSFET (labeled "N-ch"). The source of the N-channel FET is connected to ground. A resistor labeled "R" is connected between the drain of the P-channel FET and the "CMOS Hysteresis input". Another resistor labeled "R (Pull-down)" is connected between the "CMOS Hysteresis input" and ground.</p>	<ul style="list-style-type: none"> ■ CMOS Hysteresis input ■ Pull-down Resistor : 50 kΩ approx. (except Flash devices)
G	 <p>This circuit diagram shows a CMOS inverter (square symbol) connected to the drain of a P-channel MOSFET (labeled "P-ch"). The source of this P-channel FET is connected to the drain of an N-channel MOSFET (labeled "N-ch"). The source of the N-channel FET is connected to ground. The gate of the N-channel FET is connected to the drain of another P-channel MOSFET (labeled "P-ch"), which is connected to the "CMOS Hysteresis input" through a resistor labeled "R". The "CMOS Hysteresis input" is also connected to ground. Additionally, there is a TTL level input (indicated by a triangle symbol) connected to the drain of a second P-channel MOSFET (labeled "P-ch") through a resistor labeled "R". The source of this second P-channel FET is connected to the "TTL level input".</p>	<ul style="list-style-type: none"> ■ CMOS level output ■ CMOS Hysteresis input ■ TTL level input (Flash devices in Flash writer mode only)

(Continued)

(Continued)

Circuit type	Diagram	Remarks
H	 <p>This circuit diagram shows a CMOS inverter with a hysteresis input. It consists of two NMOS transistors (N-ch) and two PMOS transistors (P-ch). The top PMOS is controlled by a control signal (CNTL) and the bottom NMOS is controlled by an inverted CNTL signal. The drain of the top PMOS is connected to the source of the bottom NMOS. The drain of the bottom NMOS is connected to the output node. The source of the top PMOS is connected to Vcc. The source of the bottom NMOS is connected to ground. A resistor R is connected between the output node and a CMOS hysteresis input stage. The hysteresis input stage is represented by a triangle symbol.</p>	<ul style="list-style-type: none"> ■ CMOS level output ■ CMOS Hysteresis input ■ Programmable pull-up resistor : 50 kΩ approx.
I	 <p>This circuit diagram shows a CMOS inverter with a hysteresis input and a TTL level input. It consists of three NMOS transistors (N-ch) and three PMOS transistors (P-ch). The top PMOS is controlled by a control signal (CNTL) and the middle PMOS is controlled by an inverted CNTL signal. The drain of the top PMOS is connected to the source of the middle NMOS. The drain of the middle NMOS is connected to the source of the bottom NMOS. The drain of the bottom NMOS is connected to the output node. The source of the top PMOS is connected to Vcc. The source of the middle NMOS is connected to ground. A resistor R is connected between the output node and a CMOS hysteresis input stage. Another resistor R is connected between the output node and a TTL level input stage. The TTL level input stage is represented by a triangle symbol.</p>	<ul style="list-style-type: none"> ■ CMOS level output ■ CMOS Hysteresis input ■ TTL level input (Flash devices in Flash writer mode only) ■ Programmable pullup resistor : 50 kΩ approx.

(Continued)

Address	Register	Abbreviation	Access	Resource name	Initial value
3928 _H	Output Compare Register 0	OCCP0	R/W	Output Compare 0/1	XXXXXXXX _B
3929 _H	Output Compare Register 0	OCCP0	R/W		XXXXXXXX _B
392A _H	Output Compare Register 1	OCCP1	R/W		XXXXXXXX _B
392B _H	Output Compare Register 1	OCCP1	R/W		XXXXXXXX _B
392C _H	Output Compare Register 2	OCCP2	R/W	Output Compare 2/3	XXXXXXXX _B
392D _H	Output Compare Register 2	OCCP2	R/W		XXXXXXXX _B
392E _H	Output Compare Register 3	OCCP3	R/W		XXXXXXXX _B
392F _H	Output Compare Register 3	OCCP3	R/W		XXXXXXXX _B
3930 _H to 39FF _H	Reserved				
3A00 _H to 3AFF _H	Reserved for CAN 0 Interface.				
3B00 _H to 3BFF _H	Reserved for CAN 0 Interface.				
3C00 _H to 3CFF _H	Reserved for CAN 1 Interface.				
3D00 _H to 3DFF _H	Reserved for CAN 1 Interface.				
3E00 _H to 3FFF _H	Reserved				

■ Read/write notation

R/W : Reading and writing permitted
 R : Read-only
 W : Write-only

■ Initial value notation

0 : Initial value is "0".
 1 : Initial value is "1".
 X : Initial value is undefined.
 - : Initial value is unused.

Note: Any write access to reserved addresses in I/O map should not be performed. A read access to reserved addresses results in reading "X".

(Continued)

*1 : The interrupt request flag is cleared by the EI²OS interrupt clear signal.

*2 : The interrupt request flag is cleared by the EI²OS interrupt clear signal. A stop request is available.

Notes :

- N/A : The interrupt request flag is not cleared by the EI²OS interrupt clear signal.
- For a peripheral module with two interrupt causes for a single interrupt number, both interrupt request flags are cleared by the EI²OS interrupt clear signal.
- At the end of EI²OS, the EI²OS clear signal will be asserted for all the interrupt flags assigned to the same interrupt number. If one interrupt flag starts the EI²OS and in the meantime another interrupt flag is set by a hardware event, the later event is lost because the flag is cleared by the EI²OS clear signal caused by the first event. So it is recommended not to use the EI²OS for this interrupt number.
- If EI²OS is enabled, EI²OS is initiated when one of the two interrupt signals in the same interrupt control register (ICR) is asserted. This means that different interrupt sources share the same EI²OS Descriptor which should be unique for each interrupt source. For this reason, when one interrupt source uses the EI²OS, the other interrupt should be disabled.

11.2 Recommended Conditions

($V_{SS} = AV_{SS} = 0.0 \text{ V}$)

Parameter	Symbol	Value			Units	Remarks
		Min	Typ	Max		
Power supply voltage	V_{CC}, AV_{CC}	4.5	5.0	5.5	V	Under normal operation : Other than MB90F548GL(S)/543G(S)/547G(S)/548G(S)
		3.5	5.0	5.5		Under normal operation when A/D converter is used : MB90F548GL(S)/543G(S)/547G(S)/548G(S)
		3.0	—	5.5	V	Under normal operation when A/D converter is not used : MB90F548GL(S)/543G(S)/547G(S)/548G(S)
Smooth capacitor	C_s	0.022	0.1	1.0	μF	*
Operating temperature	T_A	-40	—	+105	$^{\circ}\text{C}$	

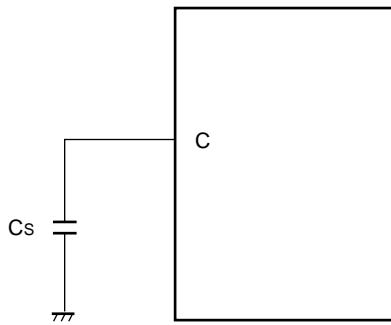
*: Use a ceramic capacitor or a capacitor of better 4. AC characteristics. The bypass capacitor should be greater than this capacitor.

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

■ C Pin Connection Diagram



(Continued)

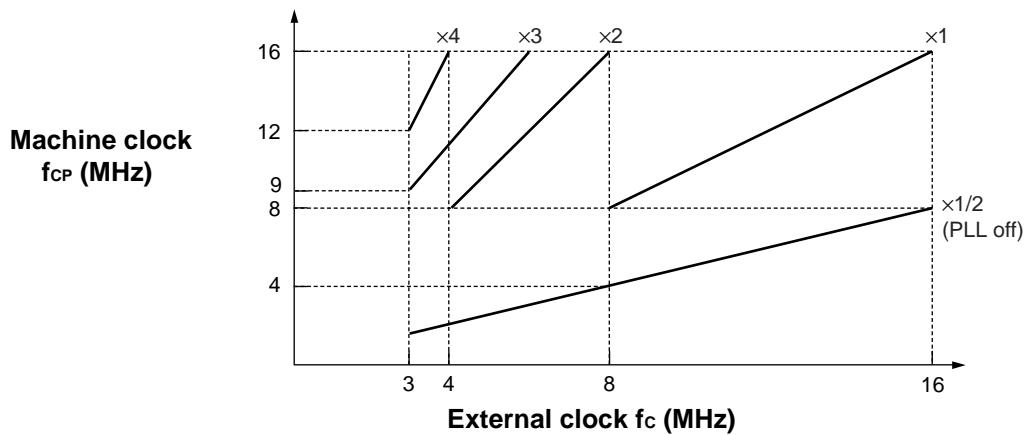
(MB90543G(S)/547G(S)/548G(S)/F548GL(S): V_{CC} = 3.5 V to 5.5 V, V_{SS} = AV_{SS} = 0.0 V, T_A = -40 °C to +105 °C)

(Other than MB90543G(S)/547G(S)/548G(S)/F548GL(S): V_{CC} = 5.0 V ± 10%, V_{SS} = AV_{SS} = 0.0 V, T_A = -40 °C to +105 °C)

Parameter	Symbol	Pin name	Condition	Value			Units	Remarks		
				Min	Typ	Max				
Power supply current*	I _{CC}	V _{CC}	Internal frequency : 16 MHz, At normal operating	—	40	55	mA			
			Internal frequency : 16 MHz, At Flash programming/erasing	—	50	70	mA	Flash device		
	I _{CCS}		Internal frequency : 16 MHz, At sleep mode	—	12	20	mA			
			V _{CC} = 5.0 V ± 10%, Internal frequency : 2 MHz, At pseudo timer mode	—	300	600	μA			
	I _{CTS}			—	600	1100	μA	MB90F548GL (S) only		
				—	200	400	μA	MB90543G(S)/547G(S)/548(S) only		
	I _{CCL}		Internal frequency : 8 kHz, At sub operation, T _A = 25 °C	—	400	750	μA	MB90F548GL only		
				—	50	100	μA	MASK ROM		
				—	150	300	μA	Flash device		
	I _{CCLS}		Internal frequency : 8 kHz, At sub sleep, T _A = 25 °C	—	15	40	μA			
	I _{CCT}		Internal frequency : 8 kHz, At timer mode, T _A = 25 °C	—	7	25	μA			
	I _{CCH1}		At stop, T _A = 25 °C	—	5	20	μA			
	I _{CCH2}		At hardware standby mode, T _A = 25 °C	—	50	100	μA			
Input capacity	C _{IN}	Other than AV _{CC} , AV _{SS} , AVRH, AVR _L , C, V _{CC} , V _{SS}	—	—	5	15	pF			

* : The power supply current testing conditions are when using the external clock.

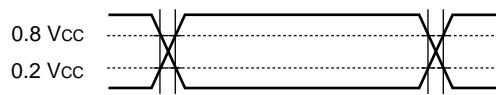
■ External clock frequency and Machine clock frequency



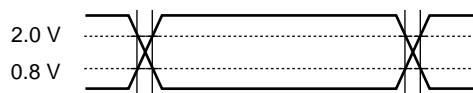
AC characteristics are set to the measured reference voltage values below.

■ Input signal waveform

Hysteresis Input Pin

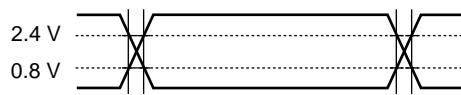


TTL Input Pin

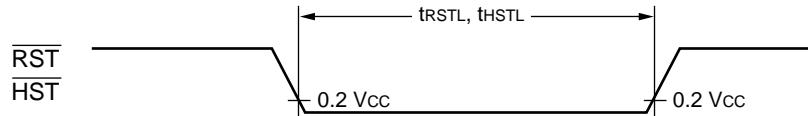


■ Output signal waveform

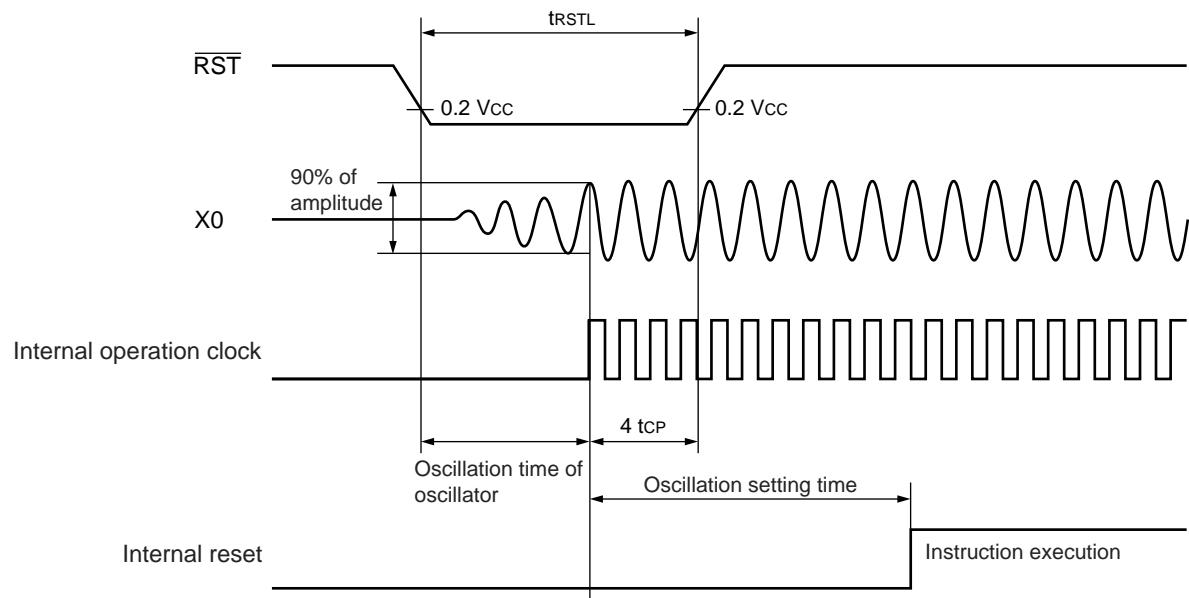
Output Pin

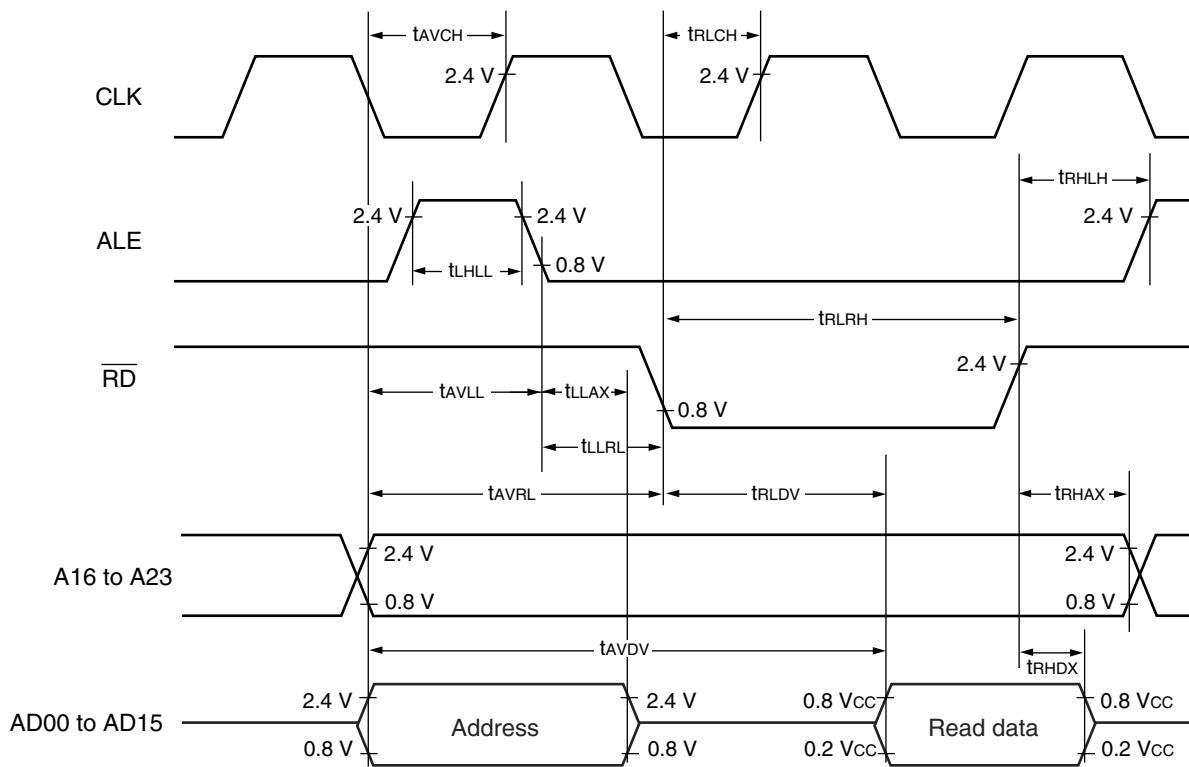


- In under normal operation, pseudo timer mode, sub-clock mode, sub-sleep mode, timer mode



- In stop mode



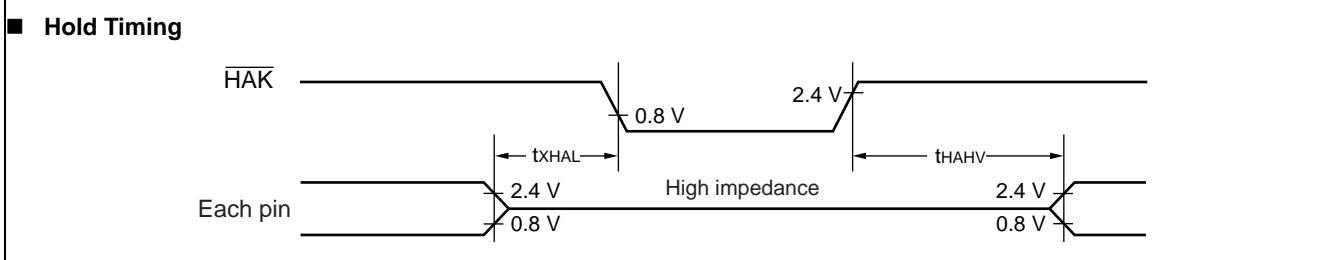
■ Bus Timing (Read)


11.4.8 Hold Timing

(MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 3.5\text{ V}$ to 5.5 V , $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)
 (Other than MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Units	Remarks
				Min	Max		
Pin floating $\rightarrow \overline{\text{HAK}}\downarrow$ time	t_{XHAL}	$\overline{\text{HAK}}$	—	30	t_{CP}	ns	
$\overline{\text{HAK}}\uparrow$ time \rightarrow Pin valid time	t_{HAHV}	$\overline{\text{HAK}}$	—	t_{CP}	$2 t_{CP}$	ns	

Note : There is more than 1 cycle from the time HRQ is read to the time the $\overline{\text{HAK}}$ is changed.



11.4.9 UART0/1, Serial I/O Timing

(MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 3.5\text{ V}$ to 5.5 V , $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)
 (Other than MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Units	Remarks
				Min	Max		
Serial clock cycle time	t_{SCYC}	SCK0 to SCK2	Internal clock operation output pins are $C_L = 80\text{ pF} + 1\text{ TTL}$.	8 t_{CP}	—	ns	
$SCK\downarrow \rightarrow$ SOT delay time	t_{SLOV}	SCK0 to SCK2, SOT0 to SOT2		— 80	80	ns	
Valid SIN $\rightarrow SCK\uparrow$	t_{IVSH}	SCK0 to SCK2, SIN0 to SIN2		100	—	ns	
$SCK\uparrow \rightarrow$ Valid SIN hold time	t_{SHIX}	SCK0 to SCK2, SIN0 to SIN2		60	—	ns	
Serial clock "H" pulse width	t_{SHSL}	SCK0 to SCK2	External clock operation output pins are $C_L = 80\text{ pF} + 1\text{ TTL}$.	4 t_{CP}	—	ns	
Serial clock "L" pulse width	t_{SLSH}	SCK0 to SCK2		4 t_{CP}	—	ns	
$SCK\downarrow \rightarrow$ SOT delay time	t_{SLOV}	SCK0 to SCK2, SOT0 to SOT2		—	150	ns	
Valid SIN $\rightarrow SCK\uparrow$	t_{IVSH}	SCK0 to SCK2, SIN0 to SIN2		60	—	ns	
$SCK\uparrow \rightarrow$ Valid SIN hold time	t_{SHIX}	SCK0 to SCK2, SIN0 to SIN2		60	—	ns	

Notes :

- AC characteristic in CLK synchronized mode.
- C_L is load capacity value of pins when testing.
- For t_{CP} (Machine clock cycle time) , refer to "(1) Clock Timing".

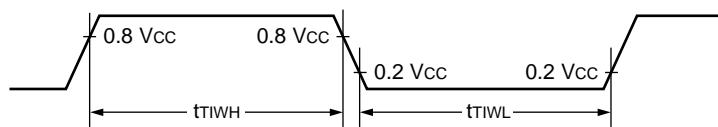
11.4.10 Timer Input Timing

(MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 3.5\text{ V}$ to 5.5 V , $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

(Other than MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Units	Remarks
				Min	Max		
Input pulse width	t_{TIWH}	$TINO$, $TIN1$	—	$4\ t_{CP}$	—	ns	
	t_{TIWL}	IN0 to IN7					

■ Timer Input Timing



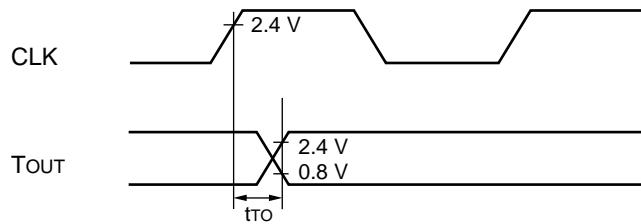
11.4.11 Timer Output Timing

(MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 3.5\text{ V}$ to 5.5 V , $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

(Other than MB90543G(S)/547G(S)/548G(S)/F548GL(S): $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = AV_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Units	Remarks
				Min	Max		
$CLK \uparrow \rightarrow T_{OUT}$ change time	t_{ro}	$TOT0$, $TOT1$, PPG0 to PPG3	—	30	—	ns	

■ Timer Output Timing



11.5 A/D Converter

11.5.1 Electrical Characteristics

($V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $3.0 \text{ V} \leq AVRH - AVRL$, $T_A = -40 \text{ }^{\circ}\text{C}$ to $+105 \text{ }^{\circ}\text{C}$)

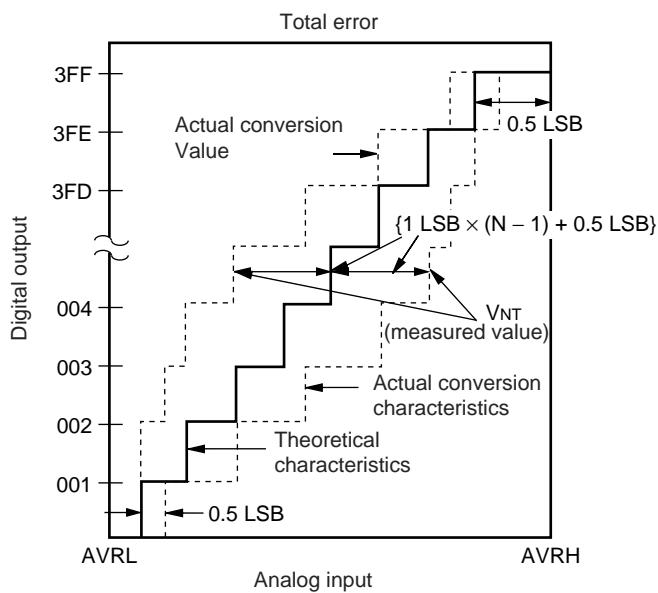
Parameter	Symbol	Pin name	Value			Units	Remarks
			Min	Typ	Max		
Resolution	—	—	—	—	10	bit	
Conversion error	—	—	—	—	± 5.0	LSB	
Nonlinearity error	—	—	—	—	± 2.5	LSB	
Differential nonlinearity error	—	—	—	—	± 1.9	LSB	
Zero transition voltage	V_{OT}	AN0 to AN7	AVRL - 3.5 LSB	AVRL + 0.5 LSB	AVRL + 4.5 LSB	V	
Full scale transition voltage	V_{FST}	AN0 to AN7	AVRH - 6.5 LSB	AVRH - 1.5 LSB	AVRH + 1.5 LSB	V	
Compare time	—	—	352 t _{CP}	—	—	ns	Internal frequency : 16 MHz
Sampling time	—	—	64 t _{CP}	—	—	ns	Internal frequency : 16 MHz
Analog port input current	I_{AIN}	AN0 to AN7	-1	—	1	μA	$V_{CC} = AV_{CC} = 5.0 \text{ V} \pm 1\%$
Analog input voltage range	V_{AIN}	AN0 to AN7	AVRL	—	AVRH	V	
Reference voltage range	—	AVRH	AVRL + 2.7	—	AV _{CC}	V	
	—	AVRL	0	—	AVRH - 2.7	V	
Power supply current	I_A	AV _{CC}	—	5	—	mA	
	I_{AH}	AV _{CC}	—	—	5	μA	*
Reference voltage supply current	I_R	AVRH	—	400	600	μA	Flash device
			—	140	260	μA	MASK ROM
	I_{RH}	AVRH	—	—	5	μA	*
Offset between input channels	—	AN0 to AN7	—	—	4	LSB	

* : When not using an A/D converter, this is the current ($V_{CC} = AV_{CC} = AVRH = 5.0 \text{ V}$) when the CPU is stopped.

Note: The functionality of the A/D converter is only guaranteed for $V_{CC} = 5.0 \text{ V} \pm 10\%$ (also for MB90543G(S)/547G(S)/548G(S)/F548G(S)/F548GL(S)).

11.5.2 A/D Converter Glossary

- Resolution : Analog changes that are identifiable with the A/D converter
- Linearity error : The deviation of the straight line connecting the zero transition point ("00 0000 0000" ↔ "00 0000 0001") with the full-scale transition point ("11 1111 1110" ↔ "11 1111 1111") from actual conversion characteristics
- Differential linearity error : The deviation of input voltage needed to change the output code by 1 LSB from the theoretical value
- Total error : The total error is defined as a difference between the actual value and the theoretical value, which includes zero-transition error/full-scale transition error and linearity error.



$$1 \text{ LSB} = (\text{Theoretical value}) \frac{\text{AVRH} - \text{AVRL}}{1024} [\text{V}]$$

$$V_{OT} \text{ (Theoretical value)} = \text{AVRL} + 0.5 \text{ LSB} [\text{V}]$$

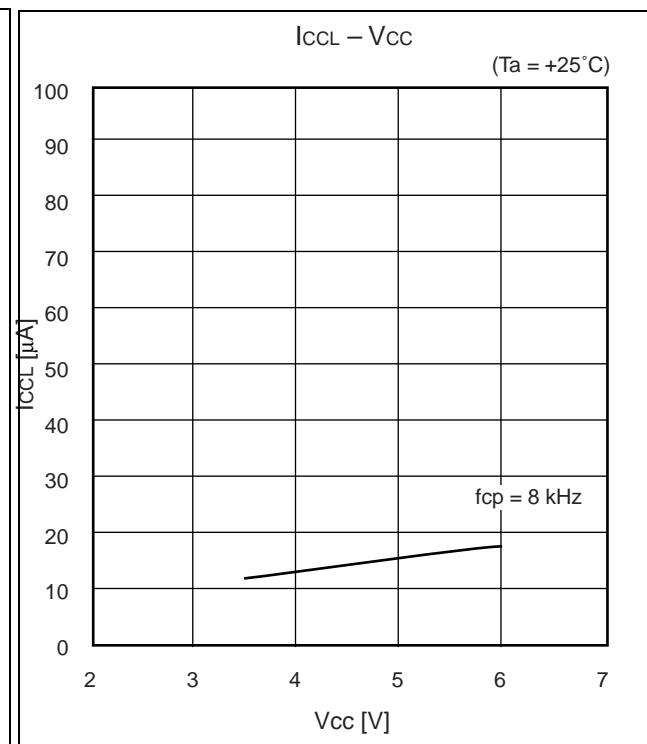
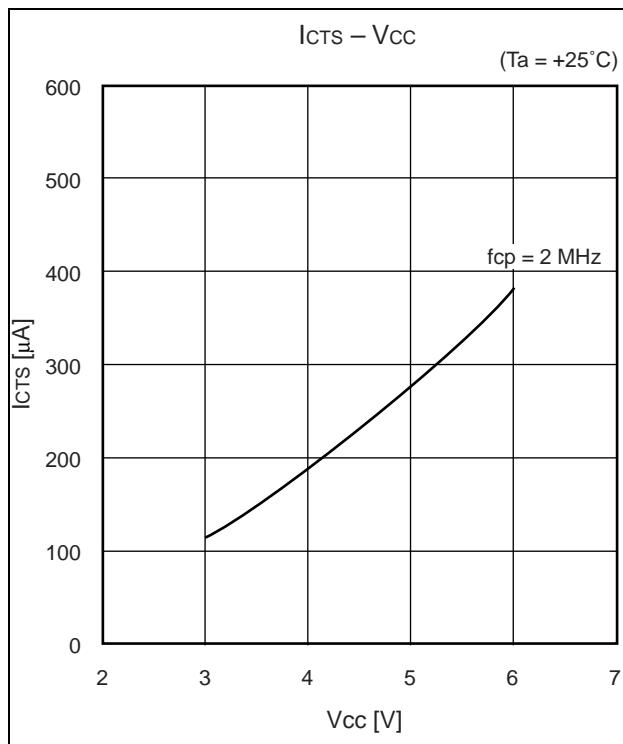
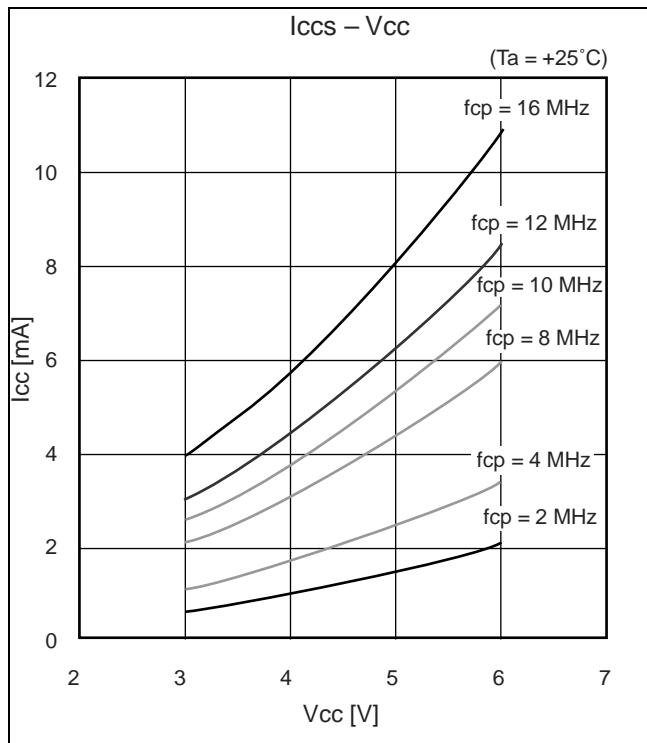
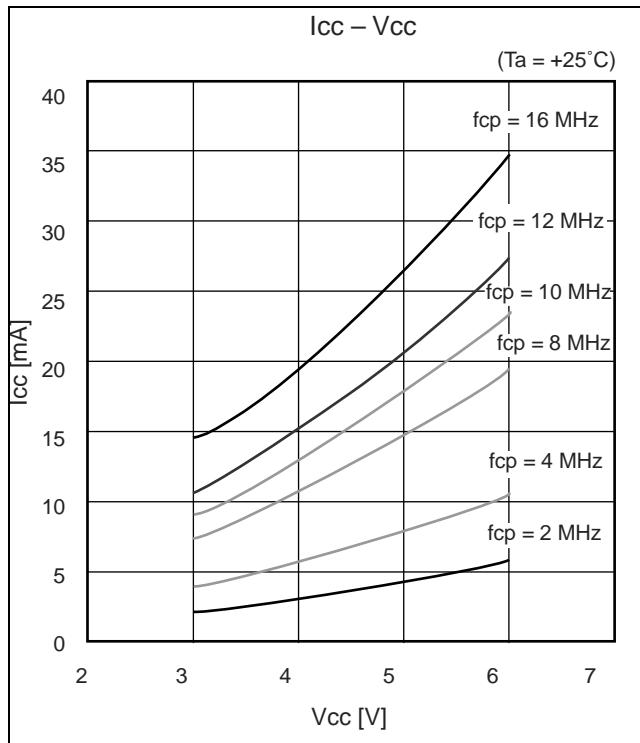
$$V_{FST} \text{ (Theoretical value)} = \text{AVRH} - 1.5 \text{ LSB} [\text{V}]$$

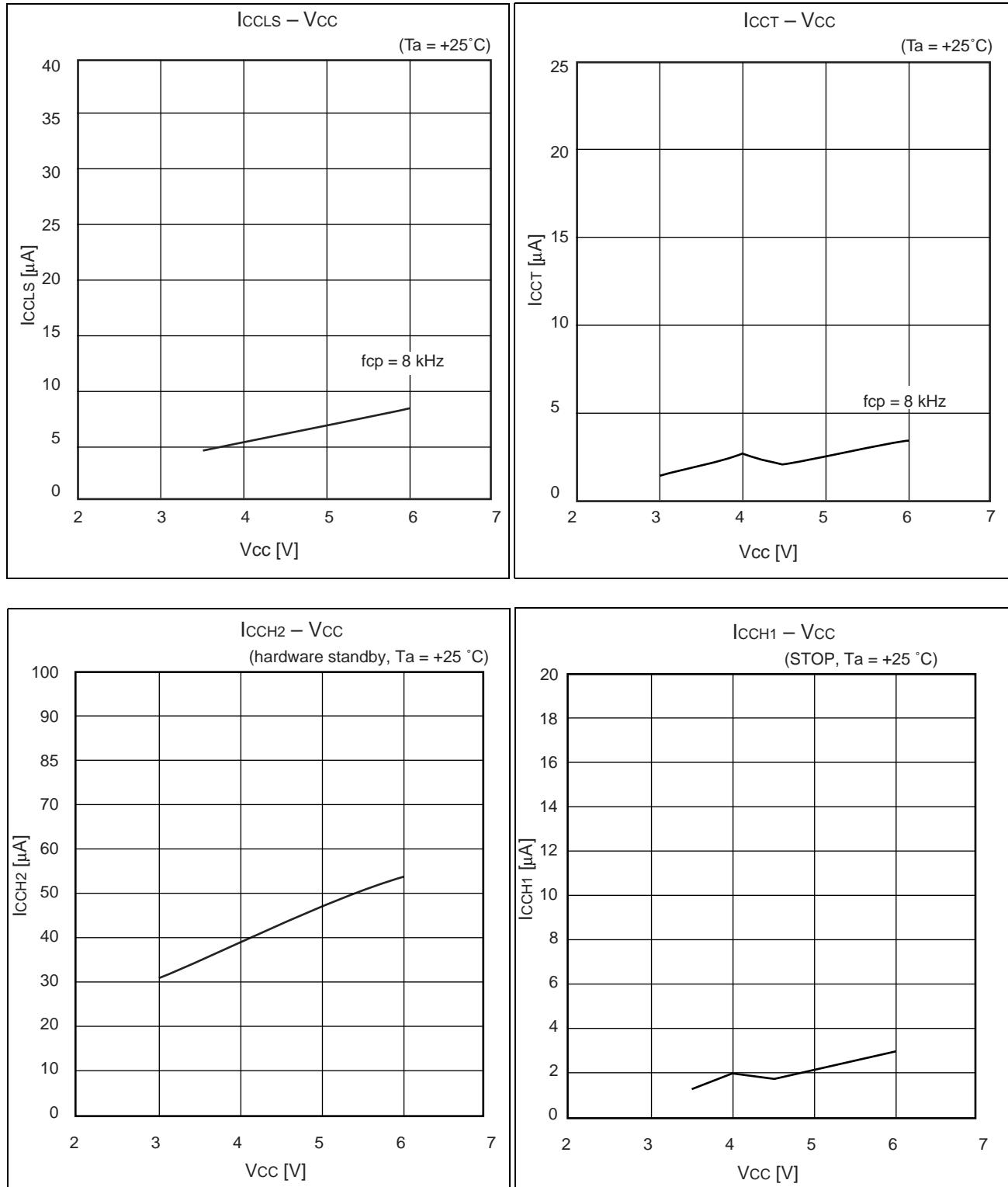
$$\text{Total error for digital output } N = \frac{V_{NT} - \{1 \text{ LSB} \times (N - 1) + 0.5 \text{ LSB}\}}{1 \text{ LSB}} [\text{LSB}]$$

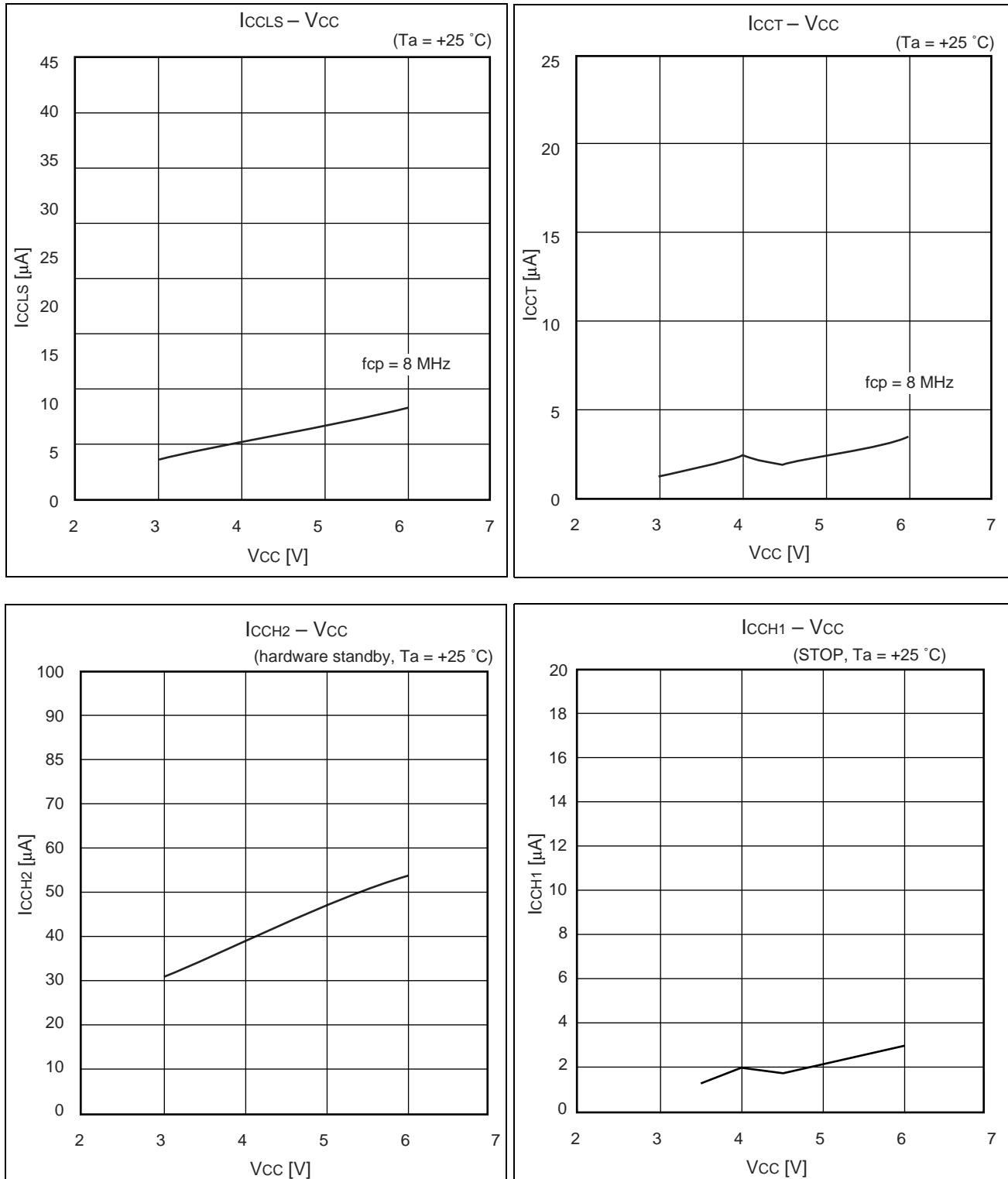
V_{NT} : Voltage at a transition of digital output from $(N - 1)$ to N

(Continued)

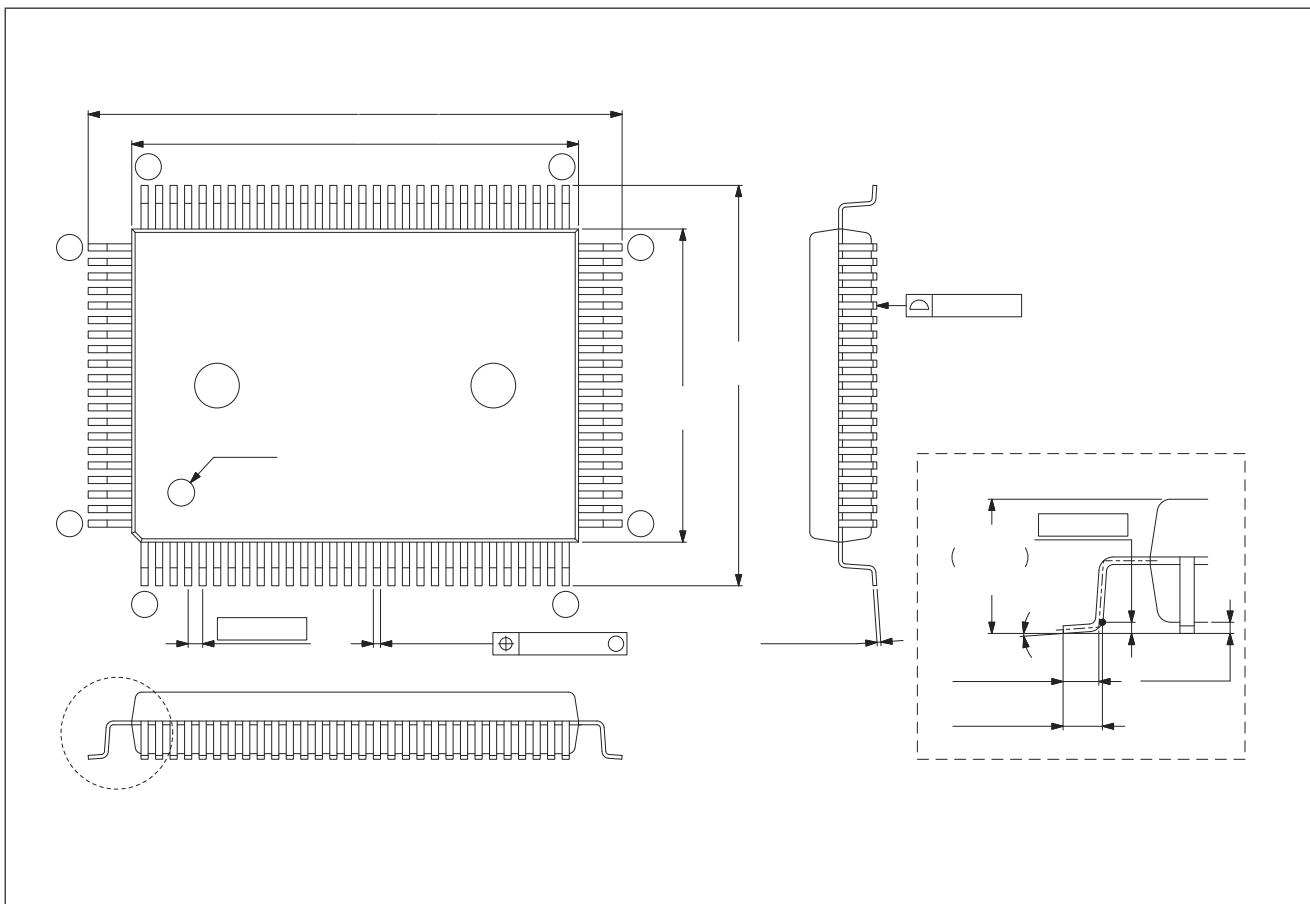
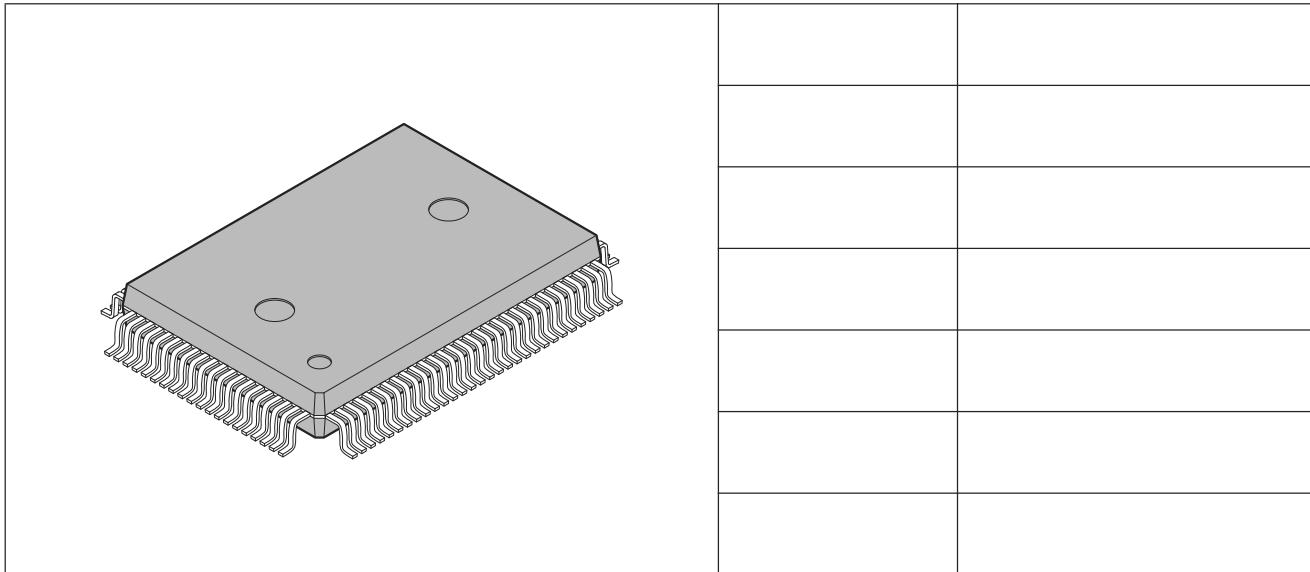
■ Power supply current (MB90549G)







14. Package Dimensions



(Continued)

15. Major Changes

Spansion Publication Number: DS07-13703-7E

Section	Change Results
■ PRODUCT LINEUP	Changed the name in peripheral resource. 16-bit I/O Timer → 16-bit Free-run Timer
■ I/O CIRCUIT TYPE	Changed the name of input typ. Hysteresis → CMOS Hysteresis HYS → CMOS Hysteresis
■ BLOCK DIAGRAM	Changed the arrow direction of SOT1 signal at UART1(SCI). “←→” (input/output) → “←” (output)
■ I/O MAP	Changed the text of “Note”.
■ INTERRUPT MAP	Changed the name of peripheral resource of the pin number: #19. I/O Timer → 16-bit Free-run Timer
■ ELECTRICAL CHARACTERISTICS 2. Recommended Conditions	Changed the remarks of “parameter: Power supply voltage”.
3. DC Characteristics	Changed the maximum value of symbol : VILM of parameter: Input voltage. V _{CC} + 0.3 → V _{SS} + 0.3 Added the following remarks for parameter : Pull-down resistance. Except Flash device
4. AC Characteristics (1) Clock Timing	Added the value when using an external clock in Oscillation frequency and Clock cycle time on (1) Clock Timing for parameter. Added the item of A/D converter operation range in figure of “■ Guaranteed PLL operation range”
(3) Reset and Hardware Standby Input Timing	Changed the following item. (3) Reset and Hardware Standby Input Timing Remarks: In sub-clock mode, sub-sleep mode, timer mode 2t _{LCP} → 2t _{LLCP}
(4) Power On Reset	Changed as follows; Due to repetitive operation → Waiting time until power-on
5. A/D Converter	Changed the unit of Zero transition voltage and Full scale transition voltage. mV → V
■ ORDERING INFORMATION	Added the MB90F548GLPMC in Part Numbers.

NOTE: Please see “Document History” about later revised information.

Document History

Document Title: MB90F543G(S)/546G(S)/548G(S)/549G(S)/549G(S)/V540G/MB90543G(S)/547G(S)/548G(S)/F548GL(S) CMOS F2MC-16LX MB90540G/545G Series 16-bit Proprietary Microcontroller Document Number: 002-07696				
Revision ECN Orig. of Change Submission Date Description of Change				
**	—	AKIH	11/13/2008	Migrated to Cypress and assigned document number 002-07696. No change to document contents or format.
*A	5537115	AKIH	11/30/2016	Updated to Cypress template